

JCS11N90WT

主要参数 MAIN CHARACTERISTICS

| | |
|-----------------------------|--------|
| ID | 11 A |
| V _{DSS} | 900 V |
| R _{dson(@Vgs=10V)} | 1.10 Ω |
| Q _g | 66 nC |

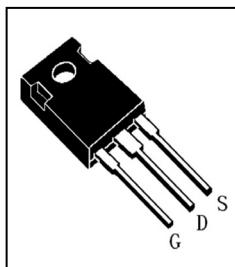
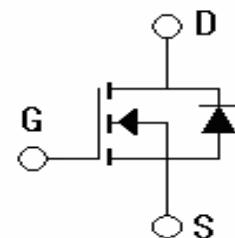
用途

- 高频开关电源
 - 电子镇流器
 - UPS 电源
- APPLICATIONS**
- High efficiency switch mode power supplies
 - Electronic lamp ballasts based on half bridge
 - UPS

产品特性

- 低栅极电荷
 - 低 C_{rss} (典型值 22pF)
 - 开关速度快
 - 产品全部经过雪崩测试
 - 高抗 dv/dt 能力
 - RoHS 产品
- FEATURES**
- Low gate charge
 - Low C_{rss} (typical 22pF)
 - Fast switching
 - 100% avalanche tested
 - Improved dv/dt capability
 - RoHS product

封装 Package



订货信息 ORDER MESSAGE

| 订货型号 Order codes | 印 记 Marking | 封 装 Package | 无卤素 Halogen Free | 包 装 Packaging | 器件重量 Device Weight |
|---------------------|----------------|----------------|---------------------|------------------|-----------------------|
| JCS11N90WT-O-W-N-B | JCS11N90WT | TO-247 | 否 NO | 条管 Tube | 5.20g(typ) |



JCS11N90WT

绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^\circ\text{C}$)

| 项 目 Parameter | 符 号 Symbol | 数 值 Value | 单 位 Unit |
|---|---|--------------|---------------------|
| | | JCS11N90WT | |
| 最高漏极—源极直流电压 Drain-Source Voltage | V_{DSS} | 900 | V |
| 连续漏极电流 Drain Current -continuous | I_D $T=25^\circ\text{C}$ | 11.0 | A |
| | | 6.9* | A |
| 最大脉冲漏极电流 (注 1) Drain Current - pulse (note 1) | I_{DM} | 44 | A |
| 最高栅源电压 Gate-Source Voltage | V_{GSS} | ± 30 | V |
| 单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy(note 2) | E_{AS} | 970 | mJ |
| 雪崩电流 (注 1) Avalanche Current (note 1) | I_{AR} | 11 | A |
| 重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1) | E_{AR} | 30.1 | mJ |
| 二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3) | dv/dt | 4.1 | V/ns |
| 耗散功率 Power Dissipation | P_D $T_c=25^\circ\text{C}$ -Derate above 25°C | 277 | W |
| | | 2.22 | W/ $^\circ\text{C}$ |
| 最高结温及存储温度 Operating and Storage Temperature Range | T_J , T_{STG} | -55~+150 | $^\circ\text{C}$ |
| 引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes | T_L | 300 | $^\circ\text{C}$ |

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature



JCS11N90WT

电特性 ELECTRICAL CHARACTERISTICS

| 项目 Parameter | 符号 Symbol | 测试条件 Tests conditions | 最小 Min | 典型 Typ | 最大 Max | 单位 Units |
|---|------------------------------|---|-----------|-----------|-----------|---------------|
| 关态特性 Off -Characteristics | | | | | | |
| 漏—源击穿电压 Drain-Source Voltage | BV_{DSS} | $I_D=250\mu A, V_{GS}=0V$ | 900 | - | - | V |
| 击穿电压温度特性 Breakdown Voltage Temperature Coefficient | $\Delta BV_{DSS}/\Delta T_J$ | $I_D=250\mu A$, referenced to $25^\circ C$ | - | 0.98 | - | V/ $^\circ C$ |
| 零栅压下漏极漏电流 Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=900V, V_{GS}=0V, T_C=25^\circ C$ | - | - | 1 | μA |
| | | $V_{DS}=720V, T_C=125^\circ C$ | - | - | 10 | μA |
| 正向栅极体漏电流 Gate-body leakage current, forward | I_{GSSF} | $V_{DS}=0V, V_{GS}=30V$ | - | - | 100 | nA |
| 反向栅极体漏电流 Gate-body leakage current, reverse | I_{GSSR} | $V_{DS}=0V, V_{GS}=-30V$ | - | - | -100 | nA |
| 通态特性 On-Characteristics | | | | | | |
| 阈值电压 Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D=250\mu A$ | 3.0 | - | 5.0 | V |
| 静态导通电阻 Static Drain-Source On-Resistance | $R_{DS(ON)}$ | $V_{GS}=10V, I_D=5.5A$ | - | 0.90 | 1.10 | Ω |
| 正向跨导 Forward Transconductance | g_{fs} | $V_{DS}=40V, I_D=5.5A$ (note 4) | - | 9.5 | - | S |
| 动态特性 Dynamic Characteristics | | | | | | |
| 输入电容 Input capacitance | C_{iss} | $V_{DS}=25V, V_{GS}=0V, f=1.0MHz$ | - | 2550 | 3340 | pF |
| 输出电容 Output capacitance | C_{oss} | | - | 210 | 270 | pF |
| 反向传输电容 Reverse transfer capacitance | C_{rss} | | - | 22 | 30 | pF |



电特性 ELECTRICAL CHARACTERISTICS

| 开关特性 Switching Characteristics | | | | | | | |
|---|--------------|---|---|------|-----|---------|--|
| 延迟时间 Turn-On delay time | $t_{d(on)}$ | $V_{DD}=450V, I_D=11A, R_G=25\Omega$ (note 4, 5) | - | 54 | 122 | ns | |
| 上升时间 Turn-On rise time | t_r | | - | 130 | 280 | ns | |
| 延迟时间 Turn-Off delay time | $t_{d(off)}$ | | - | 125 | 304 | ns | |
| 下降时间 Turn-Off Fall time | t_f | | - | 80 | 181 | ns | |
| 栅极电荷总量 Total Gate Charge | Q_g | $V_{DS}=720V, I_D=11A$ $V_{GS}=10V$ (note 4, 5) | - | 66 | 80 | nC | |
| 栅一源电荷 Gate-Source charge | Q_{gs} | | - | 13 | - | nC | |
| 栅一漏电荷 Gate-Drain charge | Q_{gd} | | - | 35 | - | nC | |
| 漏一源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings | | | | | | | |
| 正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current | I_S | | - | - | 11 | A | |
| 正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current | I_{SM} | | - | - | 44 | A | |
| 正向压降 Drain-Source Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=11A$ | - | - | 1.4 | V | |
| 反向恢复时间 Reverse recovery time | t_{rr} | $V_{GS}=0V, I_S=11A$ | - | 999 | - | ns | |
| 反向恢复电荷 Reverse recovery charge | Q_{rr} | $dI_F/dt=100A/\mu s$ (note 4) | - | 16.9 | - | μC | |

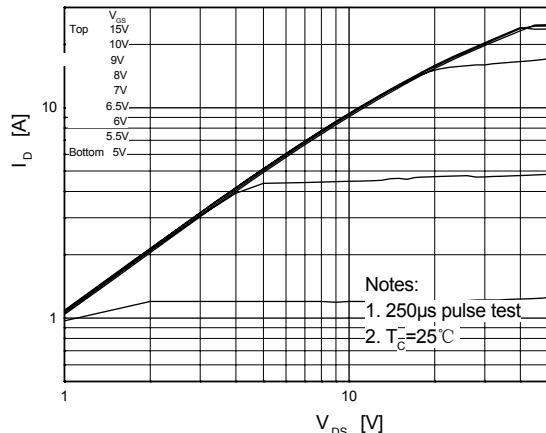
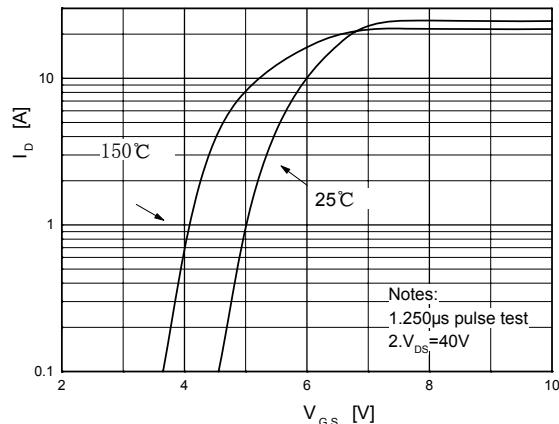
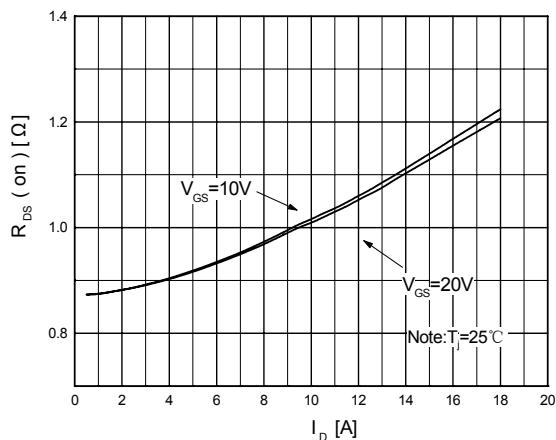
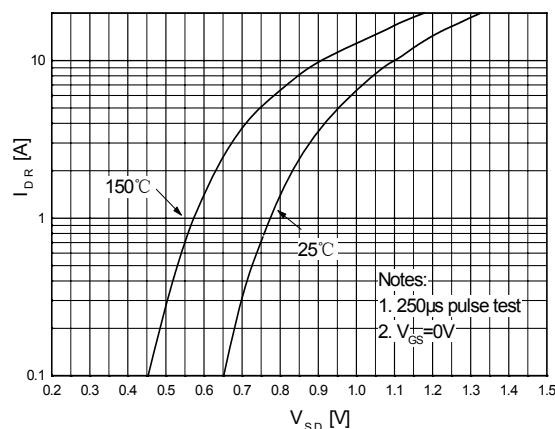
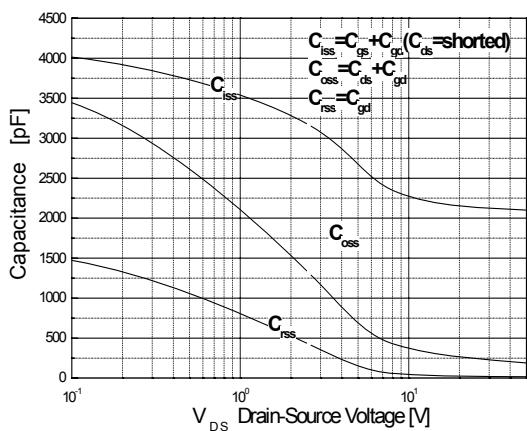
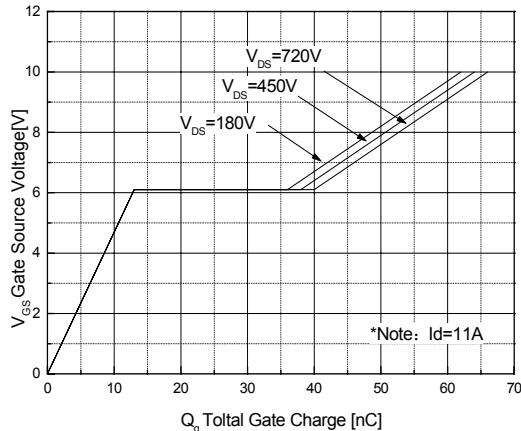
热特性 THERMAL CHARACTERISTIC

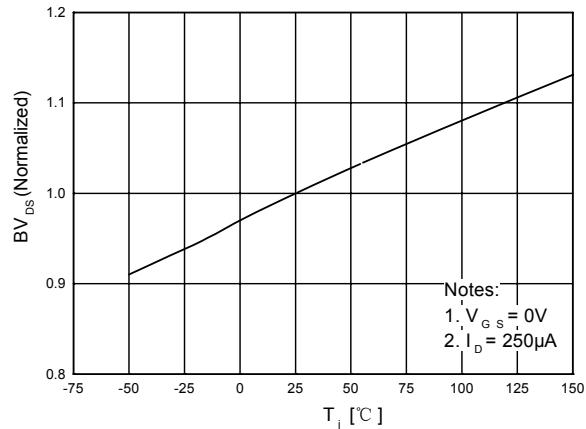
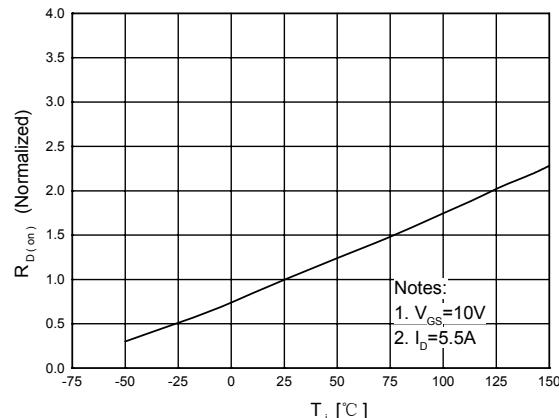
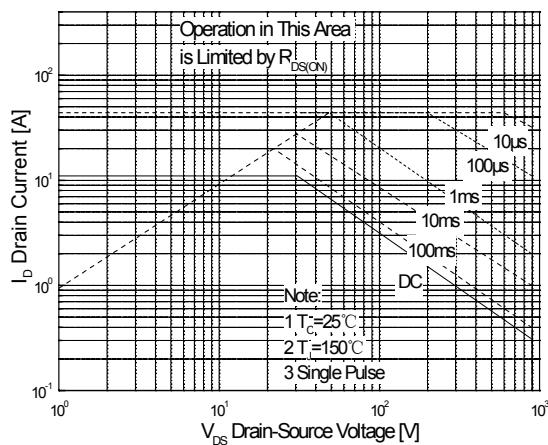
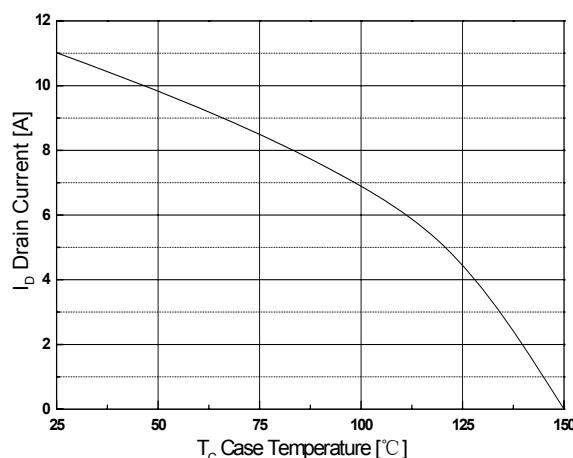
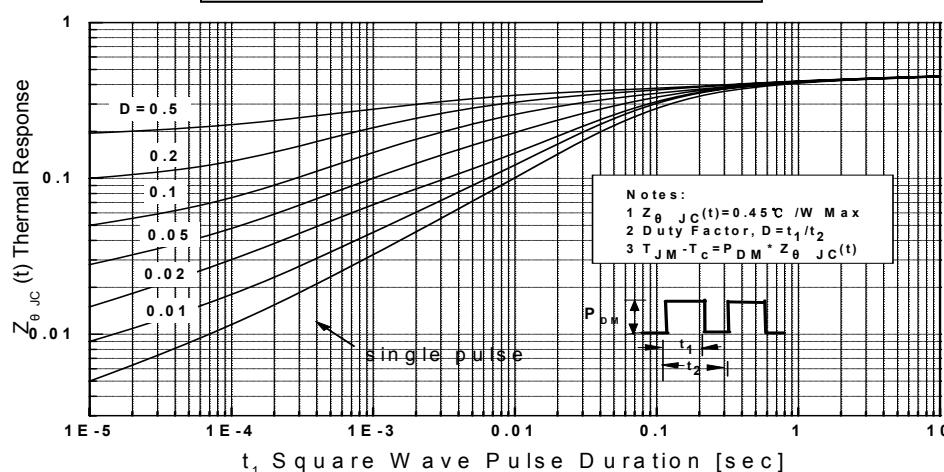
| 项 目 Parameter | 符 号 Symbol | 最大 Max | | 单 位 Unit |
|--|---------------|------------|--|-------------|
| | | JCS11N90WT | | |
| 结到管壳的热阻 Thermal Resistance, Junction to Case | $R_{th(j-c)}$ | 0.45 | | °C/W |
| 结到环境的热阻 Thermal Resistance, Junction to Ambient | $R_{th(j-A)}$ | 40 | | °C/W |

Notes:

注释:

- 1: 脉冲宽度由最高结温限制
 2: $L=15mH, I_{AS}=11A, V_{DD}=50V, R_G=25\Omega$,起始结温 $T_J=25^\circ C$
 3: $I_{SD} \leq 11A, di/dt \leq 200A/\mu s, VDD \leq BV_{DSS}$,起始结温 $T_J=25^\circ C$
 4: 脉冲测试: 脉冲宽度 $\leq 300\mu s$,占空比 $\leq 2\%$
 5: 基本与工作温度无关
- 1: Pulse width limited by maximum junction temperature
 2: $L=15mH, I_{AS}=11A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^\circ C$
 3: $I_{SD} \leq 11A, di/dt \leq 200A/\mu s, VDD \leq BV_{DSS}$, Starting $T_J=25^\circ C$
 4: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
 5: Essentially independent of operating temperature

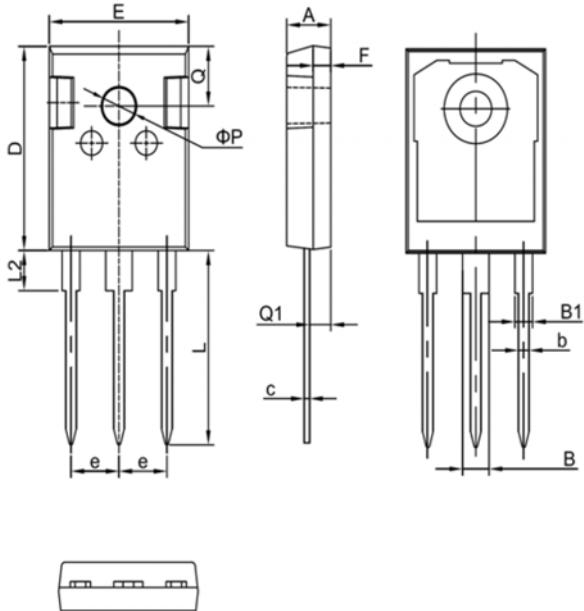
特征曲线 ELECTRICAL CHARACTERISTICS (curves)
On-Region Characteristics

Transfer Characteristics

On-Resistance Variation vs. Drain Current and Gate Voltage

Body Diode Forward Voltage Variation vs. Source Current and Temperature

Capacitance Characteristics

Gate Charge Characteristics


特征曲线 ELECTRICAL CHARACTERISTICS (curves)
**Breakdown Voltage Variation
vs. Temperature**

**On-Resistance Variation
vs. Temperature**

Maximum Safe Operating Area

**Maximum Drain Current
vs. Case Temperature**

Transient Thermal Response Curve


外形尺寸 PACKAGE MECHANICAL DATA

TO-247

单位 Unit : mm



| 符号 symbol | MIN | MAX |
|--------------|-------|-------|
| A | 4.90 | 5.10 |
| B | 2.95 | 3.35 |
| B1 | 1.95 | 2.35 |
| b | 1.15 | 1.35 |
| c | 0.50 | 0.70 |
| D | 20.90 | 21.10 |
| E | 15.70 | 15.90 |
| e | 5.34 | 5.54 |
| F | 1.90 | 2.10 |
| L | 19.40 | 20.40 |
| L2 | 4.03 | 4.23 |
| Q | 6.00 | 6.40 |
| Q1 | 2.30 | 2.50 |
| P | 3.50 | 3.70 |